

## CDSV3-4148-G/4448-G

**Reverse Voltage: 75 Volts**  
**Forward Current: 200 mA**  
**RoHS Device**



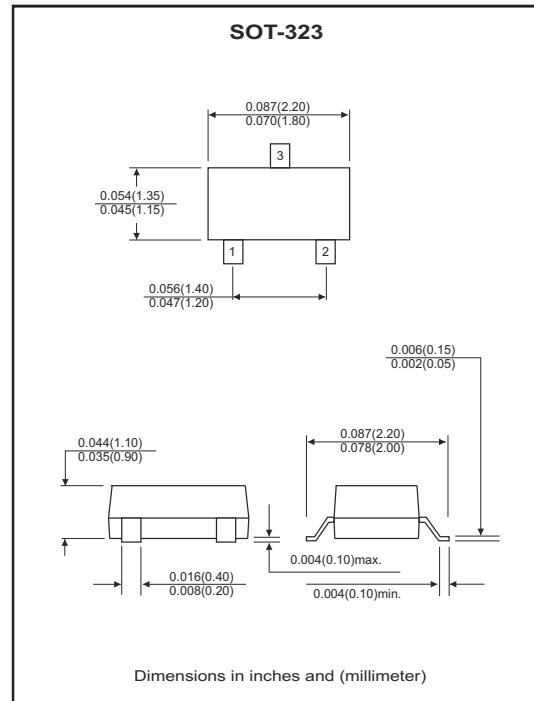
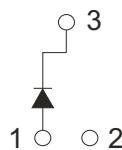
### Features

- Design for mounting on small surface.
- High speed switching.
- High mounting capability, strong surge withstand, high reliability.
- Also available in other standard case:  
 CDSF4148/4448 - 1005 size  
 CDSU4148/4448 - 0603 size

### Mechanical data

- Case: SOT-323, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Approx. weight: 0.006 grams

### Circuit diagram



### Maximum Ratings and Electrical Characteristics

(at Ta=25°C unless otherwise noted)

Parameter	Symbol	Conditions	CDSV3-4148-G	CDSV3-4448-G	Units
Repetitive peak reverse voltage	V <sub>RRM</sub>		75	75	V
Reverse voltage	V <sub>R</sub>		75	75	V
Forward current	I <sub>F</sub>		200	200	mA
Peak surge forward current	I <sub>FSM</sub>	T=1.0 μS	2	4	A
Power dissipation	P <sub>D</sub>		200	200	mW
Maximum forward voltage	V <sub>F</sub>	@I <sub>F</sub> =5mA @I <sub>F</sub> =50mA @I <sub>F</sub> =100mA	- 1 -	0.72 - 1	V
Maximum reverse current	I <sub>R</sub>	@V <sub>R</sub> =75V @V <sub>R</sub> =25V	2.5 0.025	2.5 0.025	μA
Maximum reverse recovery time	T <sub>rr</sub>	I <sub>F</sub> =I <sub>R</sub> =10mA, R <sub>L</sub> =100Ω	4	4	nS
Typical diode capacitance	C <sub>J</sub>	V <sub>R</sub> =0V, f=1.0MHz	4	4	pF
Maximum junction temperature	T <sub>J</sub>		125	125	°C
Storage temperature	T <sub>STG</sub>		-55 to +125	-55 to +125	°C

REV:A

# Small Signal Switching Diodes

**Comchip**  
SMD Diode Specialist

## RATING AND CHARACTERISTIC CURVES (CDSV3-4148-G/4448-G)

Fig.1 - Forward Characteristics

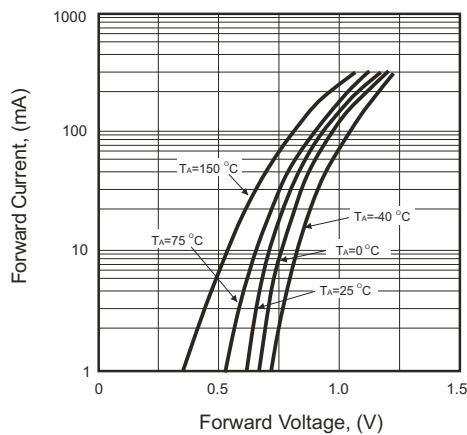


Fig.2 - Reverse Characteristics

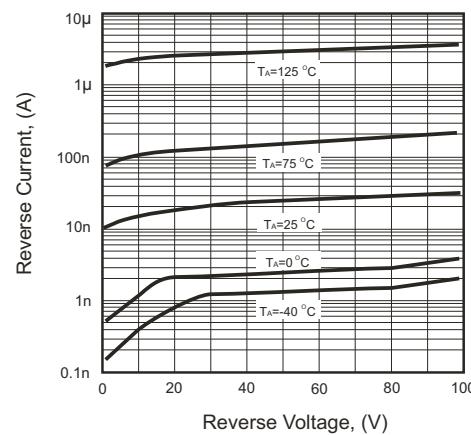


Fig.3 - Capacitance Between Terminals Characteristics

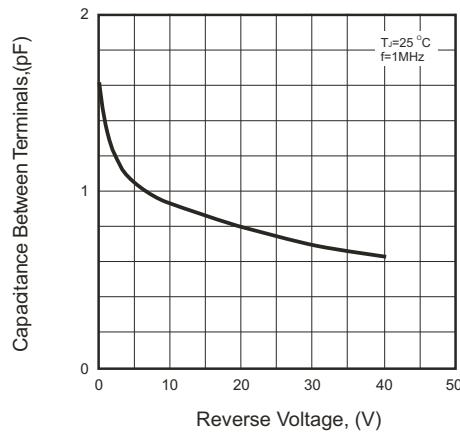


Fig.4 - Power Derating Curve

